

SWITCHMODE SERIES NPN POWER TRANSISTORS

... designed for use in high-voltage, high-speed, power switching in inductive circuit, they are particularly suited for 115 and 220 V switchmode applications such as switching regulator's, inverters, DC-DC converter, Motor Controls, Solenoid drive and Deflection circuits.

FEATURES:

* Collector-Emitter Sustaining Voltage-

$$V_{CE(sus)} = 400 \text{ V}$$

* Collector-Emitter Saturation Voltage -

$$V_{CE(sat)} = 3.0 \text{ V (Max.) @ } I_C = 8.0 \text{ A, } I_B = 2.0 \text{ A}$$

* Switching Time - $t_f = 0.7 \text{ us (Max.) @ } I_C = 5.0 \text{ A}$

* SOA and Switching Application Information.

NPN

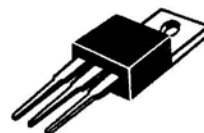
MJE13007A

8 AMPERE

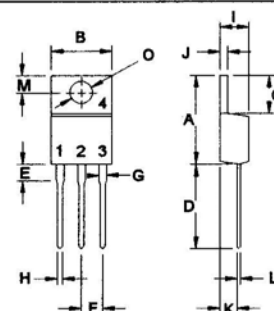
**POWER
TRANSISTORS
400 VOLTS
80 WATTS**

MAXIMUM RATINGS

| Characteristic | Symbol | MJE13007A | Unit |
|---|----------------|-------------|------------|
| Collector-Emitter Voltage | V_{CEO} | 400 | V |
| Collector-Emitter Voltage | V_{CEV} | 850 | V |
| Emitter-Base Voltage | V_{EBO} | 9 | V |
| Collector Current - Continuous | I_C | 8 | A |
| - Peak | I_{CM} | 16 | A |
| Base current | I_B | 4 | A |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 80 640 | W mW/°C |
| Operating and Storage Junction Temperature Range | T_J, T_{STG} | -65 to +150 | °C |



TO-220

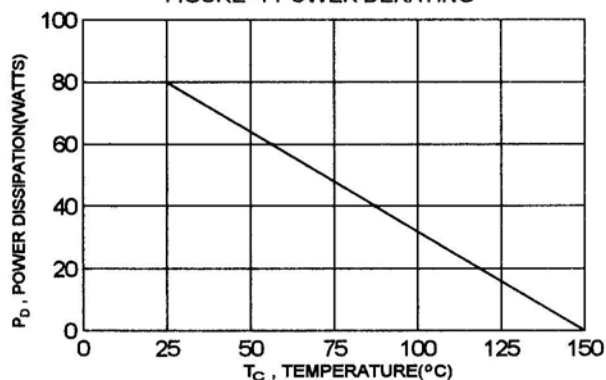


PIN 1.BASE
2.COLLECTOR
3.EMITTER
4.COLLECTOR(CASE)

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|-------------------------------------|-----------------|------|------|
| Thermal Resistance Junction to Case | $R_{\theta jc}$ | 1.56 | °C/W |

FIGURE -1 POWER DERATING



| DIM | MILLIMETERS | |
|-----|-------------|-------|
| | MIN | MAX |
| A | 14.68 | 16.00 |
| B | 9.78 | 10.42 |
| C | 5.02 | 6.60 |
| D | 13.00 | 14.62 |
| E | 3.10 | 4.19 |
| F | 2.41 | 2.67 |
| G | 1.10 | 1.67 |
| H | 0.69 | 1.01 |
| I | 3.21 | 4.98 |
| J | 1.14 | 1.40 |
| K | 2.20 | 3.30 |
| L | 0.28 | 0.61 |
| M | 2.48 | 3.00 |
| O | 3.50 | 4.00 |

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

OFF CHARACTERISTICS

| | | | | |
|---|----------------|-----|------------|----|
| Collector-Emitter Sustaining Voltage ($I_C = 10\text{ mA}, I_B = 0$) | $V_{CEO(sus)}$ | 400 | | V |
| Collector Cutoff Current ($V_{CEV} = \text{Rated Value}, V_{BE(off)} = 1.5\text{ V}$) ($V_{CEV} = \text{Rated Value}, V_{BE(off)} = 1.5\text{ V}, T_C = 100^\circ\text{C}$) | I_{CBO} | | 1.0 5.0 | mA |
| Emitter Cutoff Current ($V_{EB} = 9.0\text{ V}, I_C = 0$) | I_{EBO} | | 1.0 | mA |

ON CHARACTERISTICS (1)

| | | | | |
|---|---------------|------------|-------------------|---|
| DC Current Gain ($I_C = 2.0\text{ A}, V_{CE} = 5.0\text{ V}$) ($I_C = 5.0\text{ A}, V_{CE} = 5.0\text{ V}$) | hFE | 8.0 5.0 | 60 30 | |
| Collector-Emitter Saturation Voltage ($I_C = 2.0\text{ A}, I_B = 400\text{ mA}$) ($I_C = 5.0\text{ A}, I_B = 1.0\text{ A}$) ($I_C = 8.0\text{ A}, I_B = 2.0\text{ A}$) | $V_{CE(sat)}$ | | 1.0 2.0 3.0 | V |
| Base-Emitter Saturation Voltage ($I_C = 2.0\text{ A}, I_B = 400\text{ mA}$) ($I_C = 5.0\text{ A}, I_B = 1.0\text{ A}$) | $V_{BE(sat)}$ | | 1.2 1.6 | V |

DYNAMIC CHARACTERISTICS

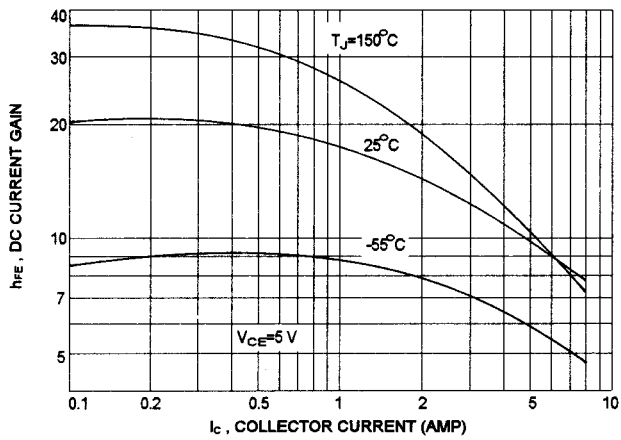
| | | | | |
|---|----------|----------|--|-----|
| Current Gain - Bandwidth Product ($I_C = 500\text{ mA}, V_{CE} = 10\text{ V}, f = 1.0\text{ MHz}$) | f_T | 4.0 | | MHz |
| Output Capacitance ($V_{CB} = 10\text{ V}, I_E = 0, f = 0.1\text{ MHz}$) | C_{ob} | 120(typ) | | pF |

SWITCHING CHARACTERISTICS

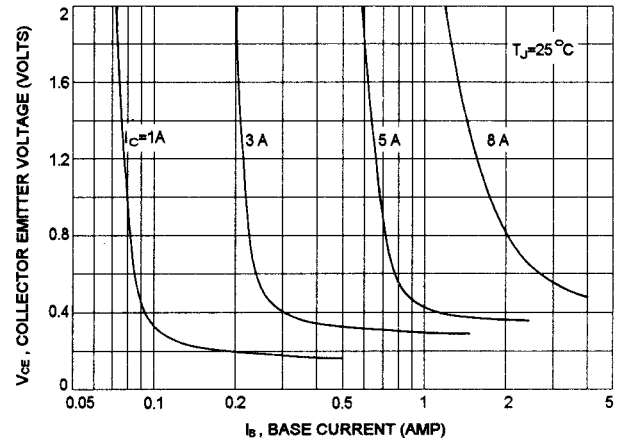
| | | | | | |
|--------------|---|-------|--|-----|----|
| Delay Time | $V_{CC} = 125\text{ V}, I_C = 5.0\text{ A}$ $I_{B1} = -I_{B2} = 1.0\text{ A},$ $t_p = 25\text{ us}, \text{Duty Cycle} \leq 1.0\%$ | t_d | | 0.1 | us |
| Rise Time | | t_r | | 1.0 | us |
| Storage Time | | t_s | | 3.0 | us |
| Fall Time | | t_f | | 0.7 | us |

(1) Pulse Test: Pulse Width = 300 us, Duty Cycle $\leq 2.0\%$

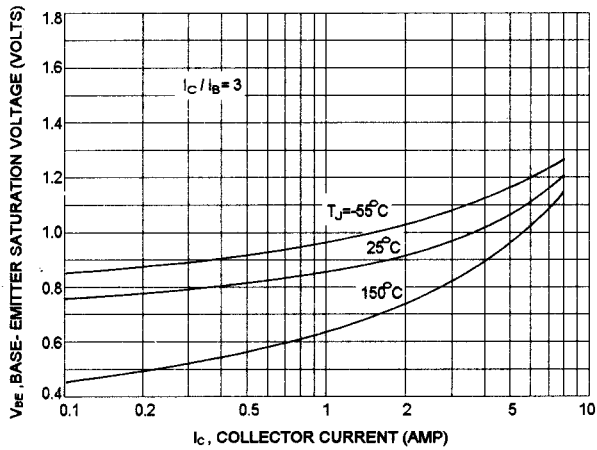
DC CURRENT GAIN



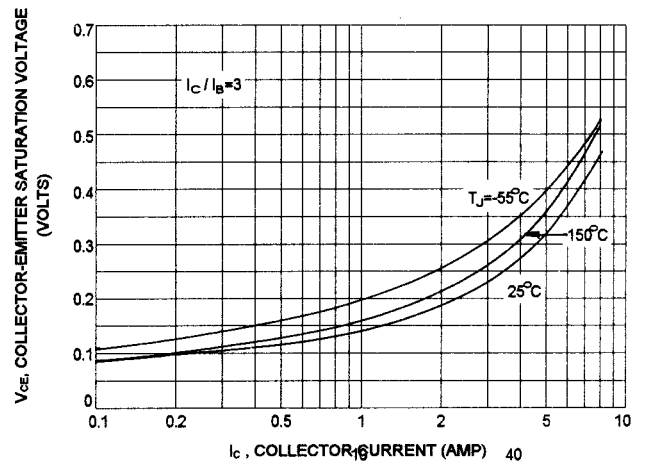
COLLECTOR SATURATION REGION



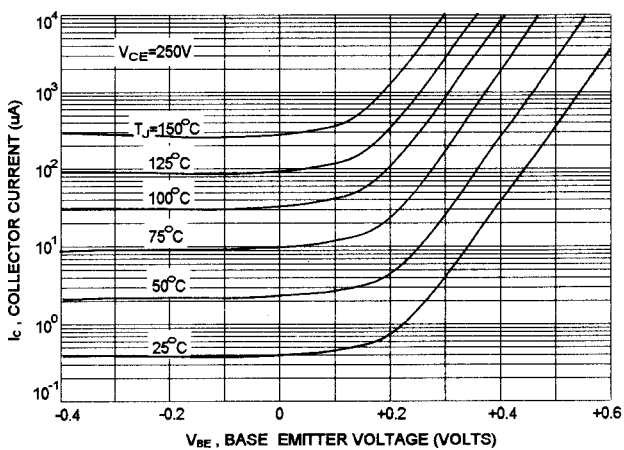
BASE-EMITTER SATURATION VOLTAGE



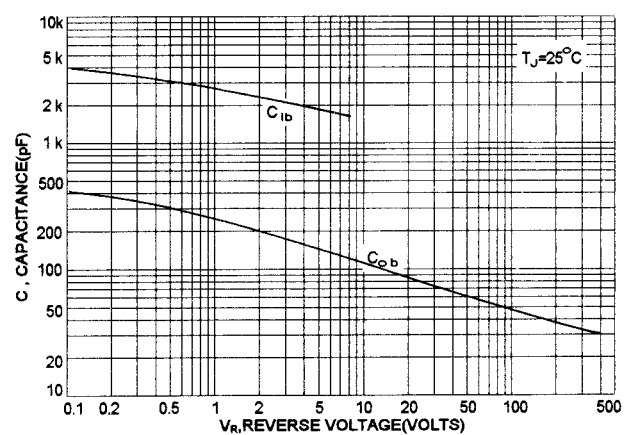
COLLECTOR-EMITTER SATURATION VOLTAGE



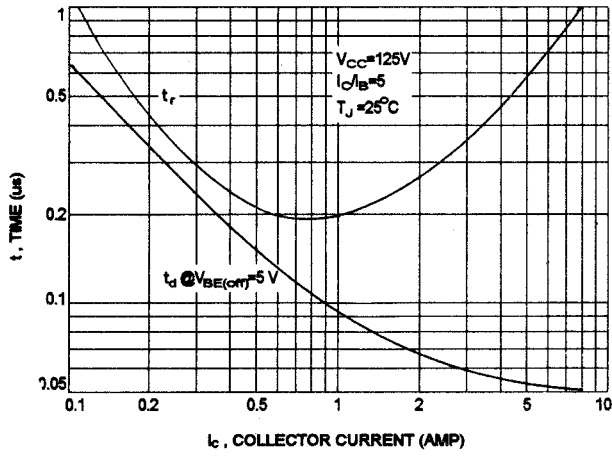
COLLECTOR CUT-OFF REGION



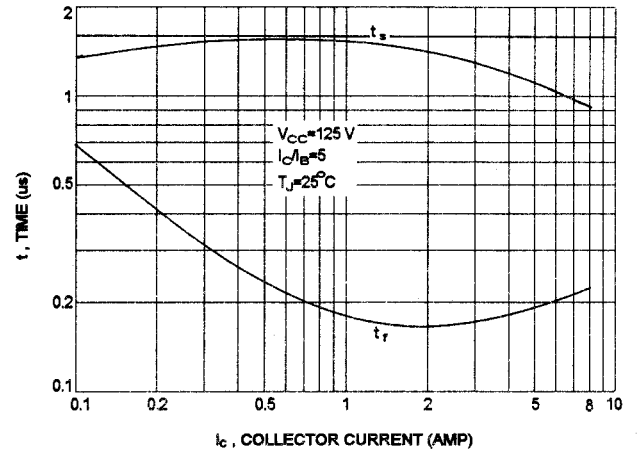
CAPACITANCE



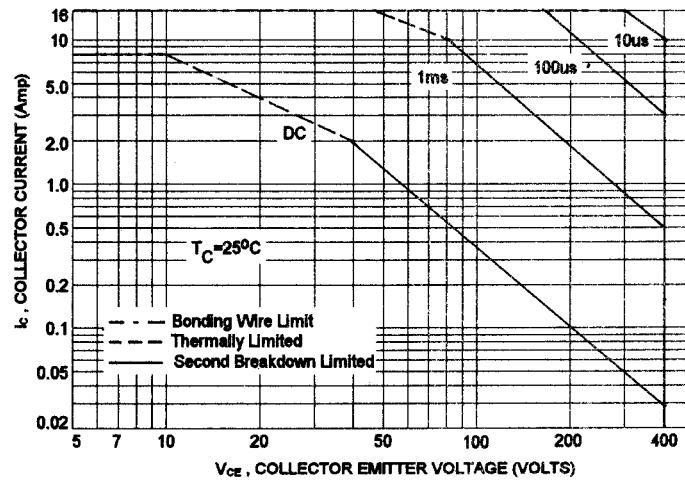
TURN-ON TIME



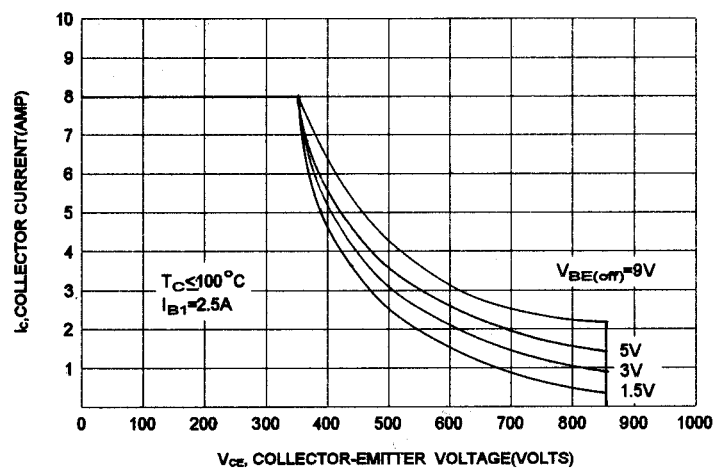
TURN-OFF TIME



ACTIVE REGION SAFE OPERATING AREA



REVERSE BIAS SWITCHING SAFE OPERATING AREA



Notice

MOSPEC reserves the rights to make changes of the content herein the document anytime without notification. MOSPEC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies. Please refer to MOSPEC website for the last document.

MOSPEC disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially incurred.

Application shown on the herein document are examples of standard use and operation. Customers are responsible for comprehending suitable use in particular applications. MOSPEC makes no representation or warranty that such application will be suitable for the specified use without further testing or modification.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by MOSPEC for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of MOSPEC or others.

These MOSPEC products are intended for usage in general electronic equipment. Please make sure to consult with MOSPEC before you use these MOSPEC products in equipment which require specialized quality and/or reliability, and in equipment which could have major impact to the welfare of human life (atomic energy control, aeronautics , traffic control, combustion control, safety devices etc.)